DISCRETE SEMICONDUCTORS

DATA SHEET

BYV79E series Rectifier diodes ultrafast, rugged

Product specification

July 1998



NXP Semiconductors Product specification

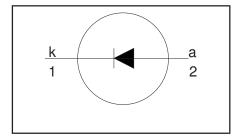
Rectifier diodes ultrafast, rugged

BYV79E series

FEATURES

- · Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performanceLow thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 150 \text{ V}/200 \text{ V}$$

$$V_F \le 0.9 \text{ V}$$

$$I_{F(AV)} = 14 \text{ A}$$

$$I_{RRM} \le 0.2 \text{ A}$$

$$t_{rr} \le 30 \text{ ns}$$

GENERAL DESCRIPTION

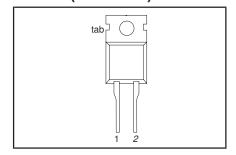
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV79E series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	cathode		

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.		UNIT
		BYV79E		-150	-200	
V _{RRM} V _{RWM}	Peak repetitive reverse voltage Crest working reverse voltage	T	-	150 150	200 200	V
V_R	Continuous reverse voltage	$T_{mb} \le 145^{\circ}C$	-	150	200	1 V I
$I_{F(AV)}$	Average forward current ¹	square wave $\delta = 0.5$; $T_{mb} \le 120 ^{\circ}\text{C}$	-	1	4	A
I _{FRM}	Repetitive peak forward current	$t = 25 \mu s; \delta = 0.5;$ $T_{mb} \le 120 ^{\circ}C$	-	2	8	A
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-	1	50 50	A A
I _{RRM} I _{RSM}	Repetitive peak reverse current Non-repetitive peak reverse current	$ \begin{array}{l} V_{\text{RWM}(\text{max})} \\ t_p = 2 \ \mu \text{s}; \ \delta = 0.001 \\ t_p = 100 \ \mu \text{s} \end{array} $	-	0.	2	A A
T _{stg}	Storage temperature Operating junction temperature		-40 -		50 50	°C °C

^{1.} Neglecting switching and reverse current losses.

ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I ~	Electrostatic discharge	Human body model;	-	8	kV
ľ	capacitor voltage	$C = 250 \text{ pF}$; $R = 1.5 \text{ k}\Omega$			

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R_{thj-mb}	Thermal resistance junction to mounting base		-	-	2	K/W
R _{th j-a}	1 0	in free air	-	60	-	K/W

STATIC CHARACTERISTICS

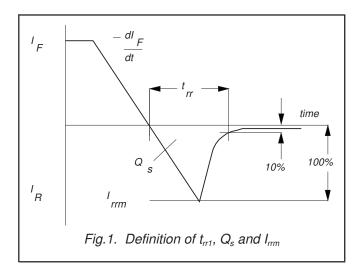
 $T_i = 25$ °C unless otherwise stated

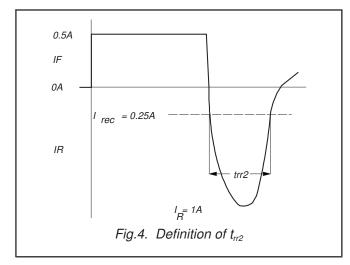
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_{\rm F} = 14 \text{ A}; T_{\rm i} = 150^{\circ}\text{C}$	-	0.83	0.90	V
· .		$I_{\rm F} = 14 \text{A}^{\circ}$	-	0.95	1.05	V
		$I_{\rm F} = 50 \text{A}$	-	1.2	1.4	V
I _B	Reverse current	$\dot{V}_{R} = \dot{V}_{RWM}$; $T_{j} = 100 ^{\circ}\text{C}$	-	0.5	1.3	mA
''		$ V_{R} = V_{RWM}$	-	5	50	μA nC
$Q_{\rm s}$	Reverse recovery charge	$ I_{\rm F} = 2 \text{A}; V_{\rm R} \ge 30 \text{V}; -dI_{\rm F}/dt = 20 \text{A/}\mu \text{s}$	-	6	15	'nС
t _{rr1}	Reverse recovery time	$I_{\rm F} = 1 \text{ A}; V_{\rm R} \ge 30 \text{ V};$	-	20	30	ns
		$-dI_{F}/dt = 100 A/\mu s$				
t _{rr2}	Reverse recovery time	$I_{\rm F} = 0.5 \text{ A to } I_{\rm R} = 1 \text{ A}; I_{\rm rec} = 0.25 \text{ A}$ $I_{\rm F} = 1 \text{ A}; dI_{\rm F}/dt = 10 \text{ A}/\mu\text{s}$	-	13	22	ns
${\sf V}_{\sf fr}$	Forward recovery voltage	$I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	1	-	V

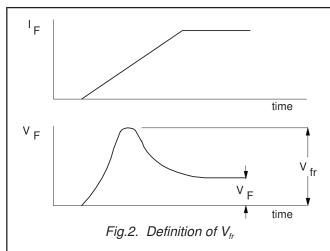
NXP Semiconductors Product specification

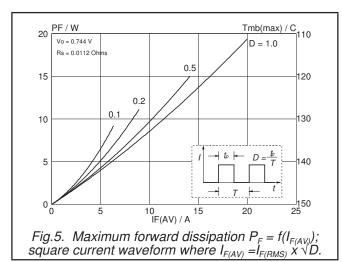
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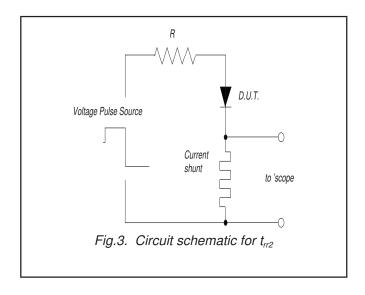
BYV79E series











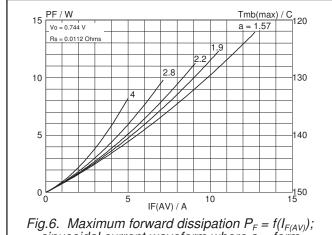
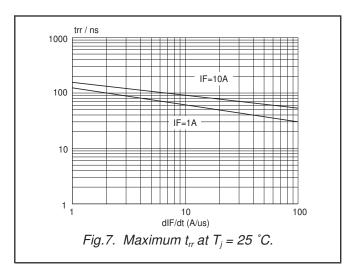


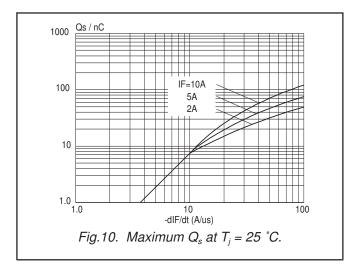
Fig.6. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor $= I_{F(RMS)} / I_{F(AV)}$.

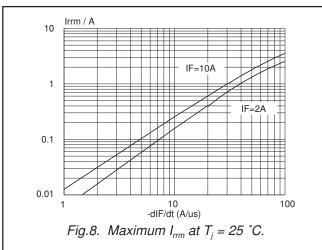
NXP Semiconductors Product specification

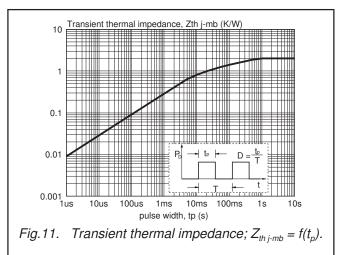
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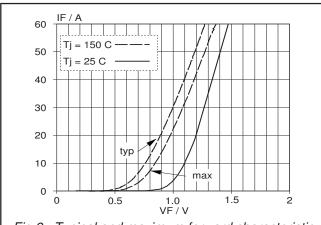
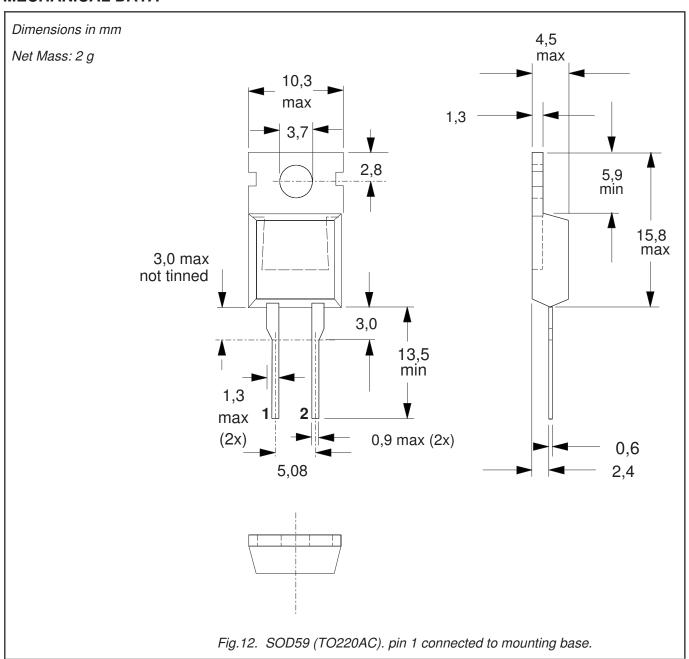


Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

NXP Semiconductors Product specification

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MECHANICAL DATA



- Refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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